

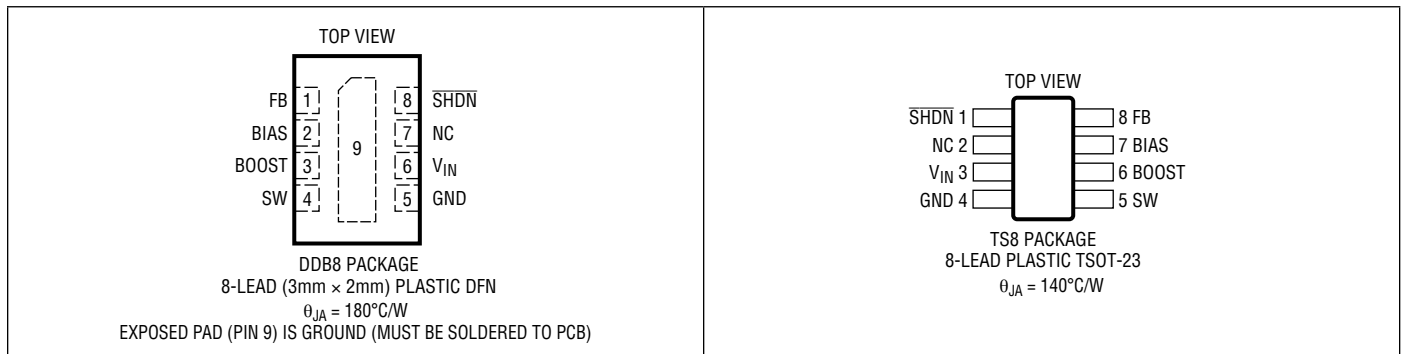
LT3470

ABSOLUTE MAXIMUM RATINGS (Note 1)

V_{IN} , SHDN Voltage	40V
BOOST Pin Voltage	47V
BOOST Pin Above SW Pin	25V
FB Voltage	5V
BIAS Voltage	25V
SW Voltage	V_{IN}
Maximum Junction Temperature	
LT3470E, LT3470I	125°C
LT3470H	150°C

Operating Temperature Range (Note 2)	
LT3470E	–40°C to 85°C
LT3470I	–40°C to 125°C
LT3470H	–40°C to 150°C
Storage Temperature Range	–65°C to 150°C
Lead Temperature (Soldering, 10 sec)	300°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT3470EDDB#TRMPBF	LT3470EDDB#TRPBF	LBPN	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 85°C
LT3470IDDB#TRMPBF	LT3470IDDB#TRPBF	LBPP	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 125°C
LT3470HDDDB#TRMPBF	LT3470HDDDB#TRPBF	LCNR	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 150°C
LT3470ETS8#PBF	LT3470ETS8#TRPBF	LTBDM	8-Lead Plastic TSOT-23	–40°C to 85°C
LT3470ITS8#PBF	LT3470ITS8#TRPBF	LTBPW	8-Lead Plastic TSOT-23	–40°C to 125°C
LT3470HTS8#PBF	LT3470HTS8#TRPBF	LTCNQ	8-Lead Plastic TSOT-23	–40°C to 150°C
LEAD BASED FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	TEMPERATURE RANGE
LT3470EDDB	LT3470EDDB#TR	LBPN	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 85°C
LT3470IDDB	LT3470IDDB#TR	LBPP	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 125°C
LT3470HDDDB	LT3470HDDDB#TR	LCNR	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 150°C
LT3470ETS8	LT3470ETS8#TR	LTBDM	8-Lead Plastic TSOT-23	–40°C to 85°C
LT3470ITS8	LT3470ITS8#TR	LTBPW	8-Lead Plastic TSOT-23	–40°C to 125°C
LT3470HTS8	LT3470HTS8#TR	LTCNQ	8-Lead Plastic TSOT-23	–40°C to 150°C

ORDER INFORMATION

AUTOMOTIVE PRODUCTS**

LT3470EDDB#WTRMPBF	LT3470EDDB#WTRPBF	LBPN	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 85°C
LT3470IDDB#WTRMPBF	LT3470IDDB#WTRPBF	LBPP	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 125°C
LT3470HDD#WTRMPBF	LT3470HDD#WTRPBF	LCNR	8-Lead (3mm × 2mm) Plastic DFN	–40°C to 150°C

Contact the factory for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container.

Tape and reel specifications. Some packages are available in 500 unit reels through designated sales channels with #TRMPBF suffix.

**Versions of this part are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. These models are designated with a #W suffix. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_{IN} = 10\text{V}$, $V_{SHDN} = 10\text{V}$, $V_{BOOST} = 15\text{V}$, $V_{BIAS} = 3\text{V}$ unless otherwise specified.

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Minimum Input Voltage		●			4	V
Quiescent Current from V_{IN}	$V_{SHDN} = 0.2\text{V}$			0.1	0.5	μA
	$V_{BIAS} = 3\text{V}$, Not Switching	●		10	18	μA
	$V_{BIAS} = 0\text{V}$, Not Switching			35	50	μA
Quiescent Current from Bias	$V_{SHDN} = 0.2\text{V}$			0.1	0.5	μA
	$V_{BIAS} = 3\text{V}$, Not Switching	●		25	60	μA
	$V_{BIAS} = 0\text{V}$, Not Switching			0.1	1.5	μA
FB Comparator Trip Voltage	V_{FB} Falling	●	1.228	1.250	1.265	V
FB Pin Bias Current (Note 3)	$V_{FB} = 1\text{V}$, E- and I-Grade			35	80	nA
		●		35	150	nA
	H-Grade	●		35	225	nA
FB Voltage Line Regulation	$4\text{V} < V_{IN} < 40\text{V}$			0.0006	0.01	%/V
Minimum Switch Off-Time (Note 5)				500		ns
Switch Leakage Current				0.7	1.5	μA
Switch V_{CESAT}	$I_{SW} = 100\text{mA}$ (TS8 Package)			215	300	mV
	$I_{SW} = 100\text{mA}$ (DD8 Package)			215		mV
Switch Top Current Limit	$V_{FB} = 0\text{V}$		250	325	435	mA
Switch Bottom Current Limit	$V_{FB} = 0\text{V}$			225		mA
Catch Schottky Drop	$I_{SH} = 100\text{mA}$ (TS8 Package)			630	775	mV
	$I_{SH} = 100\text{mA}$ (DD8 Package)			630		mV
Catch Schottky Reverse Leakage	$V_{SW} = 10\text{V}$			0.2	2	μA
Boost Schottky Drop	$I_{SH} = 30\text{mA}$			650	775	mV
Boost Schottky Reverse Leakage	$V_{SW} = 10\text{V}$, $V_{BIAS} = 0\text{V}$			0.2	2	μA
Minimum Boost Voltage (Note 4)		●		1.7	2.2	V
BOOST Pin Current	$I_{SW} = 100\text{mA}$			7	12	mA
SHDN Pin Current	$V_{SHDN} = 2.5\text{V}$			1	5	μA
SHDN Input Voltage High			2.5			V
SHDN Input Voltage Low					0.2	V

ELECTRICAL CHARACTERISTICS

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: The LT3470E is guaranteed to meet performance specifications from 0°C to 85°C. Specifications over the -40°C to 85°C operating temperature range are assured by design, characterization and correlation with statistical process controls. The LT3470I specifications

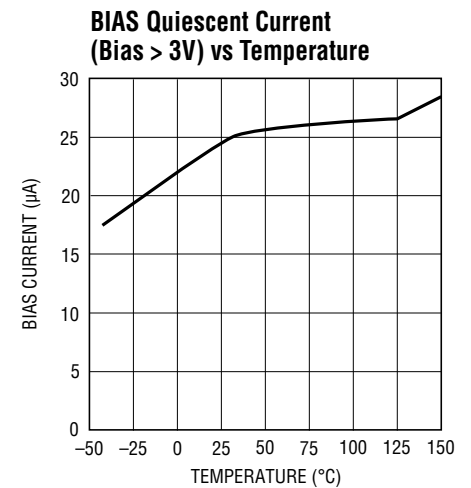
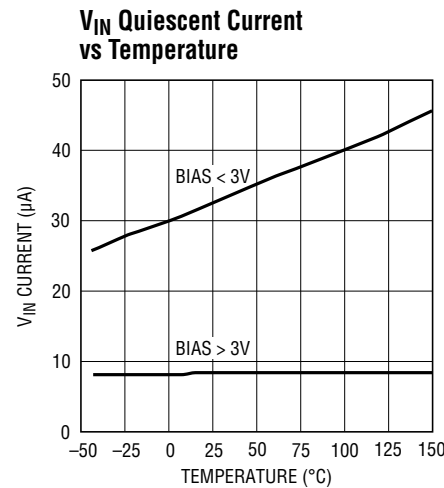
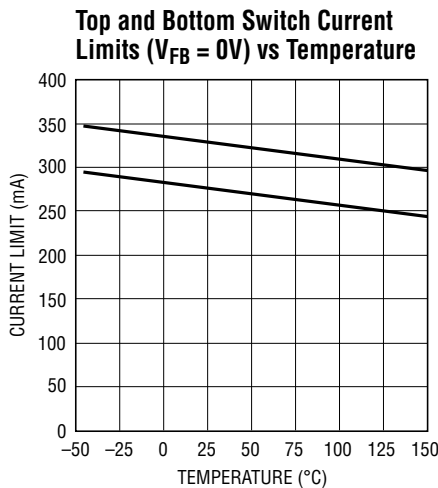
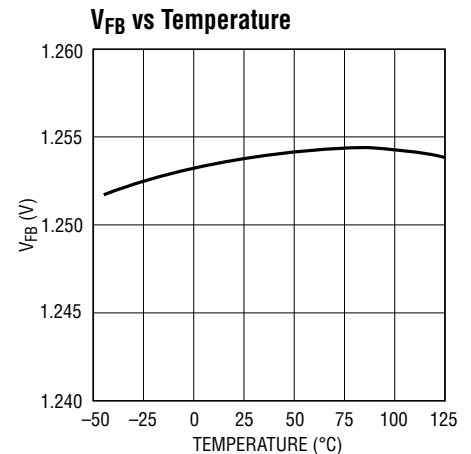
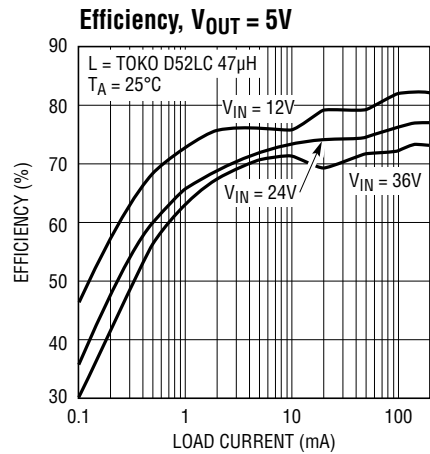
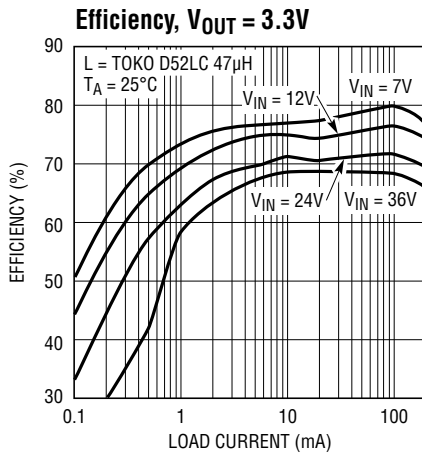
are guaranteed over the -40°C to 125°C temperature range. LT3470H specifications are guaranteed over -40°C to 150°C temperature range.

Note 3: Bias current flows out of the FB pin.

Note 4: This is the minimum voltage across the boost capacitor needed to guarantee full saturation of the switch.

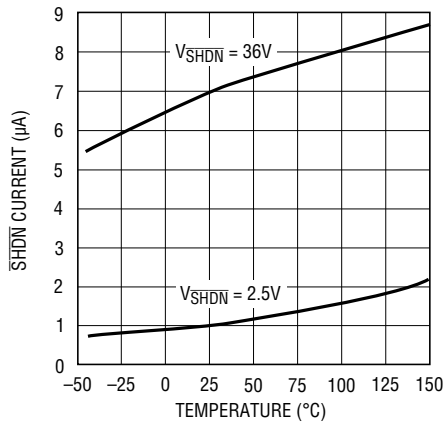
Note 5: This parameter is assured by design and correlation with statistical process controls.

TYPICAL PERFORMANCE CHARACTERISTICS



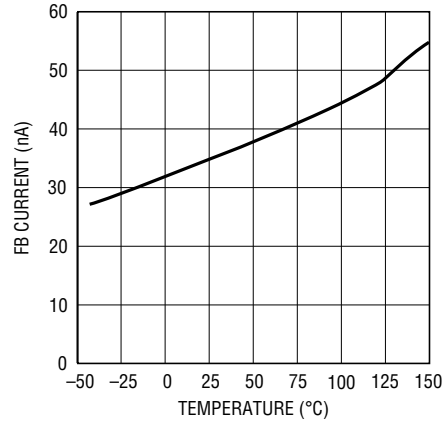
TYPICAL PERFORMANCE CHARACTERISTICS

SHDN Bias Current vs Temperature



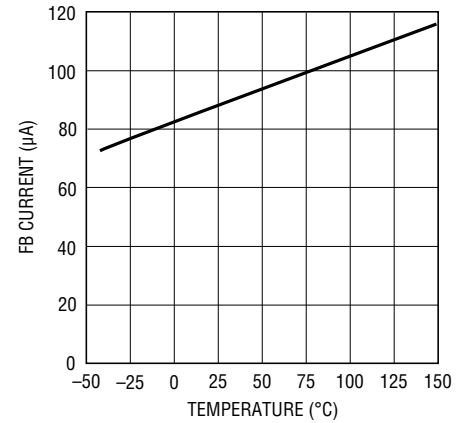
3470 G07

FB Bias Current ($V_{FB} = 1V$) vs Temperature



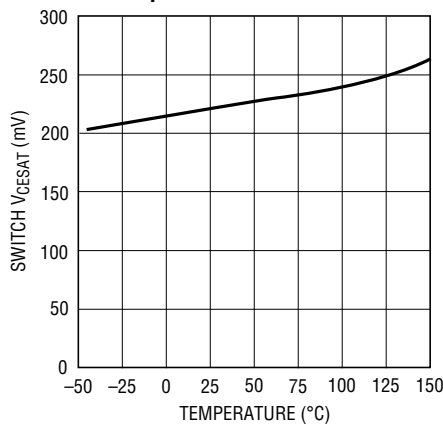
3470 G08

FB Bias Current ($V_{FB} = 0V$) vs Temperature



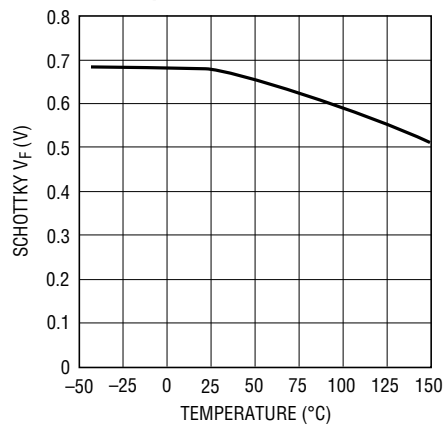
3470 G09

Switch V_{CESAT} ($I_{SW} = 100mA$) vs Temperature



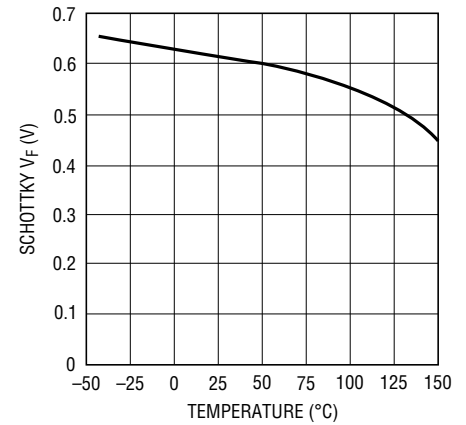
3470 G10

Boost Diode V_F ($I_F = 50mA$) vs Temperature



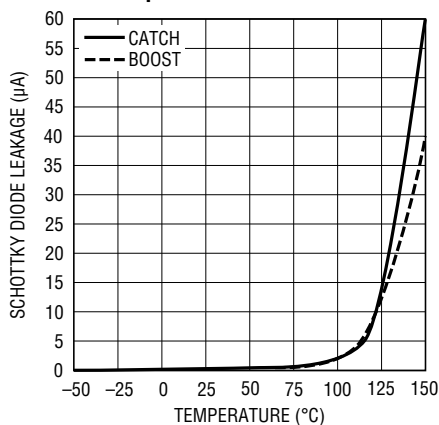
3470 G11

Catch Diode V_F ($I_F = 100mA$) vs Temperature



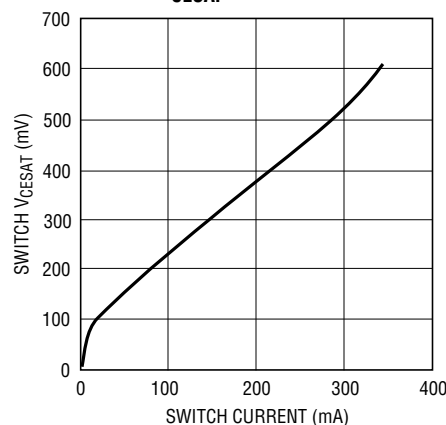
3470 G12

Diode Leakage ($V_R = 36V$) vs Temperature



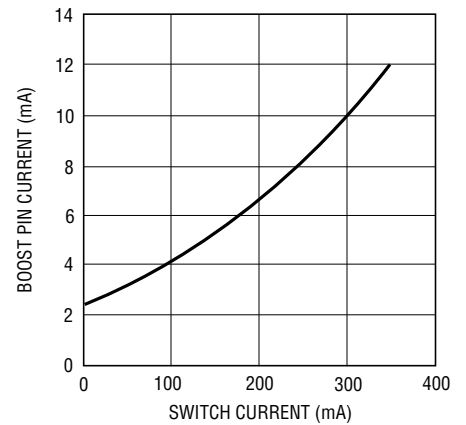
3470 G13

Switch V_{CESAT}



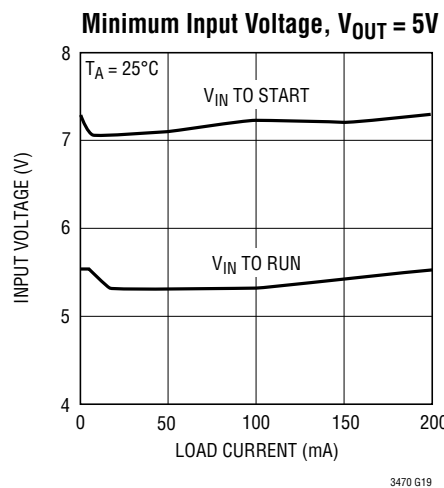
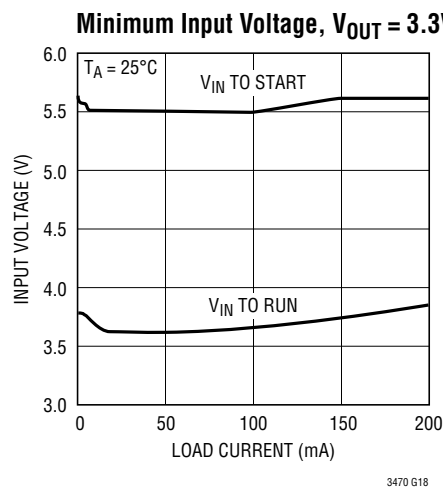
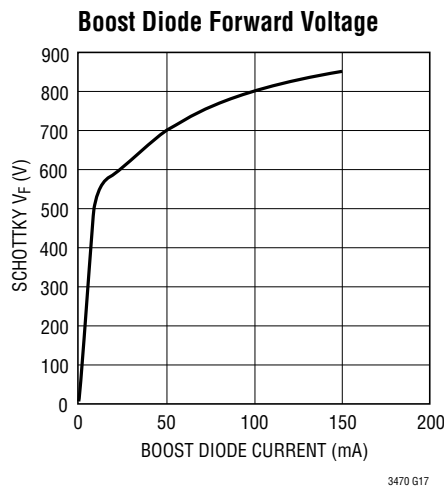
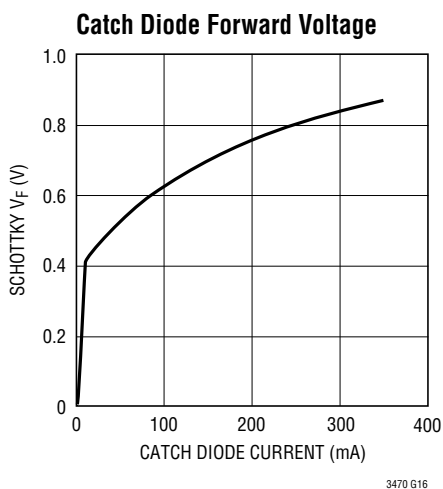
3470 G14

BOOST Pin Current



3470 G15

TYPICAL PERFORMANCE CHARACTERISTICS



OPERATION

The LT3470 uses a hysteretic control scheme in conjunction with Burst Mode operation to provide low output ripple and low quiescent current while using a tiny inductor and capacitors.

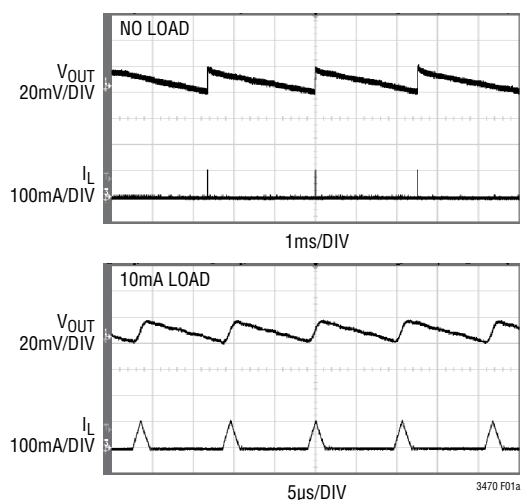
Operation can best be understood by studying the Block Diagram. An error amplifier measures the output voltage through an external resistor divider tied to the FB pin. If the FB voltage is higher than V_{REF} , the error amplifier will shut off all the high power circuitry, leaving the LT3470 in its micropower state. As the FB voltage falls, the error amplifier will enable the power section, causing the chip to begin switching, thus delivering charge to the output capacitor. If the load is light the part will alternate between micropower and switching states to keep the output in regulation (See Figure 1a). At higher loads the part will switch continuously while the error amp serves the top and bottom current limits to regulate the FB pin voltage to 1.25V (See Figure 1b).

The switching action is controlled by an RS latch and two current comparators as follows: The switch turns on, and the current through it ramps up until the top current

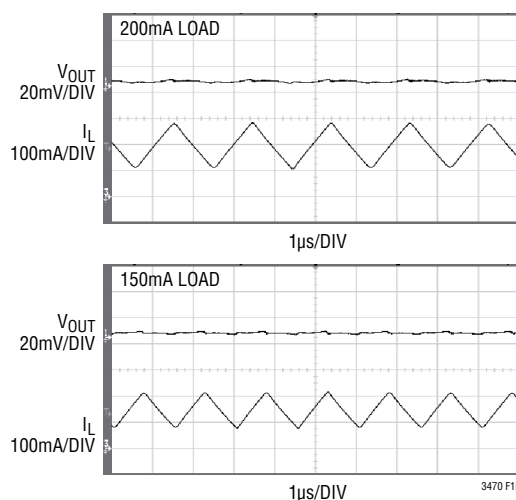
comparator trips and resets the latch causing the switch to turn off. While the switch is off, the inductor current ramps down through the catch diode. When both the bottom current comparator trips and the minimum off-time one-shot expires, the latch turns the switch back on thus completing a full cycle. The hysteretic action of this control scheme results in a switching frequency that depends on inductor value, input and output voltage. Since the switch only turns on when the catch diode current falls below threshold, the part will automatically switch slower to keep inductor current under control during start-up or short-circuit conditions.

The switch driver operates from either the input or from the BOOST pin. An external capacitor and internal diode is used to generate a voltage at the BOOST pin that is higher than the input supply. This allows the driver to fully saturate the internal bipolar NPN power switch for efficient operation.

If the $\overline{SHDN}$ pin is grounded, all internal circuits are turned off and V_{IN} current reduces to the device leakage current, typically a few nA.



(1a) Burst Mode Operation



(1b) Continuous Operation

Figure 1. Operating Waveforms of the LT3470 Converting 12V to 5V Using a 33μH Inductor and 10μF Output Capacitor

APPLICATIONS INFORMATION

Input Voltage Range

The minimum input voltage required to generate a particular output voltage in an LT3470 application is limited by either its 4V undervoltage lockout or by its maximum duty cycle. The duty cycle is the fraction of time that the internal switch is on and is determined by the input and output voltages:

$$DC = \frac{V_{OUT} + V_D}{V_{IN} - V_{SW} + V_D}$$

where V_D is the forward voltage drop of the catch diode ($\sim 0.6V$) and V_{SW} is the voltage drop of the internal switch at maximum load ($\sim 0.4V$). Given $DC_{MAX} = 0.90$, this leads to a minimum input voltage of:

$$V_{IN(MIN)} = \left(\frac{V_{OUT} + V_D}{DC_{MAX}} \right) + V_{SW} - V_D$$

This analysis assumes the part has started up such that the capacitor tied between the BOOST and SW pins is charged to more than 2V. For proper start-up, the minimum input voltage is limited by the boost circuit as detailed in the section BOOST Pin Considerations.

The maximum input voltage is limited by the absolute maximum V_{IN} rating of 40V, provided an inductor of sufficient value is used.

Inductor Selection

The switching action of the LT3470 during continuous operation produces a square wave at the SW pin that results in a triangle wave of current in the inductor. The hysteretic mode control regulates the top and bottom current limits (see Electrical Characteristics) such that the average inductor current equals the load current. For safe operation, it must be noted that the LT3470 cannot turn the switch on for less than $\sim 150ns$. If the inductor is small and the input voltage is high, the current through the switch may exceed safe operating limit before the LT3470 is able to turn off. To prevent this from happening, the following equation provides a minimum inductor value:

$$L_{MIN} = \frac{V_{IN(MAX)} \cdot t_{ON-TIME(MIN)}}{I_{MAX}}$$

where $V_{IN(MAX)}$ is the maximum input voltage for the application, $t_{ON-TIME(MIN)}$ is $\sim 150ns$ and I_{MAX} is the maximum allowable increase in switch current during a minimum switch on-time (150mA). While this equation provides a safe inductor value, the resulting application circuit may switch at too high a frequency to yield good efficiency. It is advised that switching frequency be below 1.2MHz during normal operation:

$$f = \frac{(1-DC)(V_D + V_{OUT})}{L \cdot \Delta I_L}$$

where f is the switching frequency, ΔI_L is the ripple current in the inductor ($\sim 150mA$), V_D is the forward voltage drop of the catch diode, and V_{OUT} is the desired output voltage.

If the application circuit is intended to operate at high duty cycles (V_{IN} close to V_{OUT}), it is important to look at the calculated value of the switch off-time:

$$t_{OFF-TIME} = \frac{1-DC}{f}$$

The calculated $t_{OFF-TIME}$ should be more than LT3470's minimum $t_{OFF-TIME}$ (See Electrical Characteristics), so the application circuit is capable of delivering full rated output current. If the full output current of 200mA is not required, the calculated $t_{OFF-TIME}$ can be made less than minimum $t_{OFF-TIME}$ possibly allowing the use of a smaller inductor. See Table 1 for an inductor value selection guide.

Table 1. Recommended Inductors for Loads up to 200mA

V_{OUT}	V_{IN} UP TO 16V	V_{IN} UP TO 40V
2.5V	10 μ H	33 μ H
3.3V	10 μ H	33 μ H
5V	15 μ H	33 μ H
12V	33 μ H	47 μ H

Choose an inductor that is intended for power applications. Table 2 lists several manufacturers and inductor series.

For robust output short-circuit protection at high V_{IN} (up to 40V) use at least a 33 μ H inductor with a minimum 450mA saturation current. If short-circuit performance is not required, inductors with I_{SAT} of 300mA or more may

APPLICATIONS INFORMATION

Table 2. Inductor Vendors

VENDOR	URL	PART SERIES	INDUCTANCE RANGE (μH)	SIZE (mm)
Coilcraft	www.coilcraft.com	DO1605	10 to 47	1.8 × 5.4 × 4.2
		ME3220	10 to 47	2.0 × 3.2 × 2.5
		DO3314	10 to 47	1.4 × 3.3 × 3.3
Sumida	www.sumida.com	CR32	10 to 47	3.0 × 3.8 × 4.1
		CDRH3D16/HP	10 to 33	1.8 × 4.0 × 4.0
		CDRH3D28	10 to 47	3.0 × 4.0 × 4.0
		CDRH2D18/HP	10 to 15	2.0 × 3.2 × 3.2
Toko	www.tokoam.com	DB320C	10 to 27	2.0 × 3.8 × 3.8
		D52LC	10 to 47	2.0 × 5.0 × 5.0
Würth Elektronik	www.we-online.com	WE-PD2 Typ S	10 to 47	3.2 × 4.0 × 4.5
		WE-TPC Typ S	10 to 22	1.6 × 3.8 × 3.8
Coiltronics	www.cooperet.com	SD10	10 to 47	1.0 × 5.0 × 5.0
Murata	www.murata.com	LQH43C	10 to 47	2.6 × 3.2 × 4.5
		LQH32C	10 to 15	1.6 × 2.5 × 3.2

be used. It is important to note that inductor saturation current is reduced at high temperatures—see inductor vendors for more information.

Input Capacitor

Step-down regulators draw current from the input supply in pulses with very fast rise and fall times. The input capacitor is required to reduce the resulting voltage ripple at the V_{IN} pin of the LT3470 and to force this switching current into a tight local loop, minimizing EMI. The input capacitor must have low impedance at the switching frequency to do this effectively. A 1μF to 2.2μF ceramic capacitor satisfies these requirements.

If the input source impedance is high, a larger value capacitor may be required to keep input ripple low. In this case, an electrolytic of 10μF or more in parallel with a 1μF ceramic is a good combination. Be aware that the input capacitor is subject to large surge currents if the LT3470 circuit is connected to a low impedance supply, and that some electrolytic capacitors (in particular tantalum) must be specified for such use.

Output Capacitor and Output Ripple

The output capacitor filters the inductor's ripple current and stores energy to satisfy the load current when the LT3470 is quiescent. In order to keep output voltage ripple low, the impedance of the capacitor must be low at the

LT3470's switching frequency. The capacitor's equivalent series resistance (ESR) determines this impedance. Choose one with low ESR intended for use in switching regulators. The contribution to ripple voltage due to the ESR is approximately $I_{LIM} \cdot ESR$. ESR should be less than ~150mΩ. The value of the output capacitor must be large enough to accept the energy stored in the inductor without a large change in output voltage. Setting this voltage step equal to 1% of the output voltage, the output capacitor must be:

$$C_{OUT} > 50 \cdot L \cdot \left(\frac{I_{LIM}}{V_{OUT}} \right)^2$$

where I_{LIM} is the top current limit with $V_{FB} = 0V$ (see Electrical Characteristics). For example, an LT3470 producing 3.3V with $L = 33\mu H$ requires 22μF. The calculated value can be relaxed if small circuit size is more important than low output ripple.

Sanyo's POSCAP series in B-case and provides very good performance in a small package for the LT3470. Similar performance in traditional tantalum capacitors requires a larger package (C-case). With a high quality capacitor filtering the ripple current from the inductor, the output voltage ripple is determined by the delay in the LT3470's feedback comparator. This ripple can be reduced further by adding a small (typically 22pF) phase lead capacitor between the output and the feedback pin.

APPLICATIONS INFORMATION

Ceramic Capacitors

Ceramic capacitors are small, robust and have very low ESR. However, ceramic capacitors can cause problems when used with the LT3470. Not all ceramic capacitors are suitable. X5R and X7R types are stable over temperature and applied voltage and give dependable service. Other types, including Y5V and Z5U have very large temperature and voltage coefficients of capacitance. In an application circuit they may have only a small fraction of their nominal capacitance resulting in much higher output voltage ripple than expected.

Ceramic capacitors are piezoelectric. The LT3470's switching frequency depends on the load current, and at light loads the LT3470 can excite the ceramic capacitor at audio frequencies, generating audible noise. Since the LT3470 operates at a lower current limit during Burst Mode operation, the noise is typically very quiet to a casual ear. If this audible noise is unacceptable, use a high performance electrolytic capacitor at the output. The input capacitor can be a parallel combination of a 2.2μF ceramic capacitor and a low cost electrolytic capacitor.

A final precaution regarding ceramic capacitors concerns the maximum input voltage rating of the LT3470. A ceramic input capacitor combined with trace or cable inductance forms a high quality (under damped) tank circuit. If the LT3470 circuit is plugged into a live supply, the input voltage can ring to twice its nominal value, possibly exceeding the LT3470's rating. This situation is easily avoided; see the Hot-Plugging Safely section.

BOOST and BIAS Pin Considerations

Capacitor C3 and the internal boost Schottky diode (see Block Diagram) are used to generate a boost voltage that is higher than the input voltage. In most cases a 0.22μF capacitor will work well. Figure 2 shows two ways to arrange the boost circuit. The BOOST pin must be more than 2.5V above the SW pin for best efficiency. For outputs of 3.3V and above, the standard circuit (Figure 2a) is best. For outputs between 2.5V and 3V, use a 0.47μF. For lower output voltages the boost diode can be tied to the input

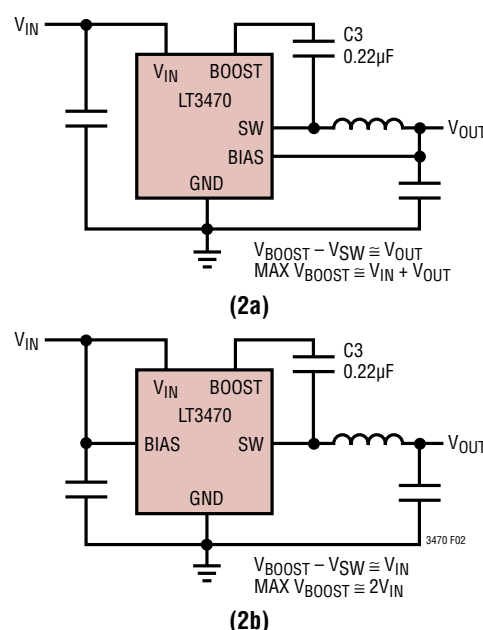


Figure 2. Two Circuits for Generating the Boost Voltage

Table 3. Capacitor Vendors

VENDOR	PHONE	URL	PART SERIES	COMMENTS
Panasonic	(714) 373-7366	www.panasonic.com	Ceramic, Polymer, Tantalum	EEF Series
Kemet	(864) 963-6300	www.kemet.com	Ceramic, Tantalum	T494, T495
Sanyo	(408) 749-9714	www.sanyovideo.com	Ceramic, Polymer, Tantalum	POSCAP
Murata	(404) 436-1300	www.murata.com	Ceramic	
AVX		www.avxcorp.com	Ceramic, Tantalum	TPS Series
Taiyo Yuden	(864) 963-6300	www.taiyo-yuden.com	Ceramic	

APPLICATIONS INFORMATION

PCB Layout

For proper operation and minimum EMI, care must be taken during printed circuit board layout. Note that large, switched currents flow in the power switch, the internal catch diode and the input capacitor. The loop formed by these components should be as small as possible. Furthermore, the system ground should be tied to the regulator ground in only one place; this prevents the switched current from injecting noise into the system ground. These components, along with the inductor and output capacitor, should be placed on the same side of the circuit board, and their connections should be made on that layer. Place a local, unbroken ground plane below these components, and tie this ground plane to system ground at one location,

ideally at the ground terminal of the output capacitor C2. Additionally, the SW and BOOST nodes should be kept as small as possible. Unshielded inductors can induce noise in the feedback path resulting in instability and increased output ripple. To avoid this problem, use vias to route the V_{OUT} trace under the ground plane to the feedback divider (as shown in Figure 5). Finally, keep the FB node as small as possible so that the ground pin and ground traces will shield it from the SW and BOOST nodes. Figure 5 shows component placement with trace, ground plane and via locations. Include vias near the GND pin, or pad, of the LT3470 to help remove heat from the LT3470 to the ground plane.

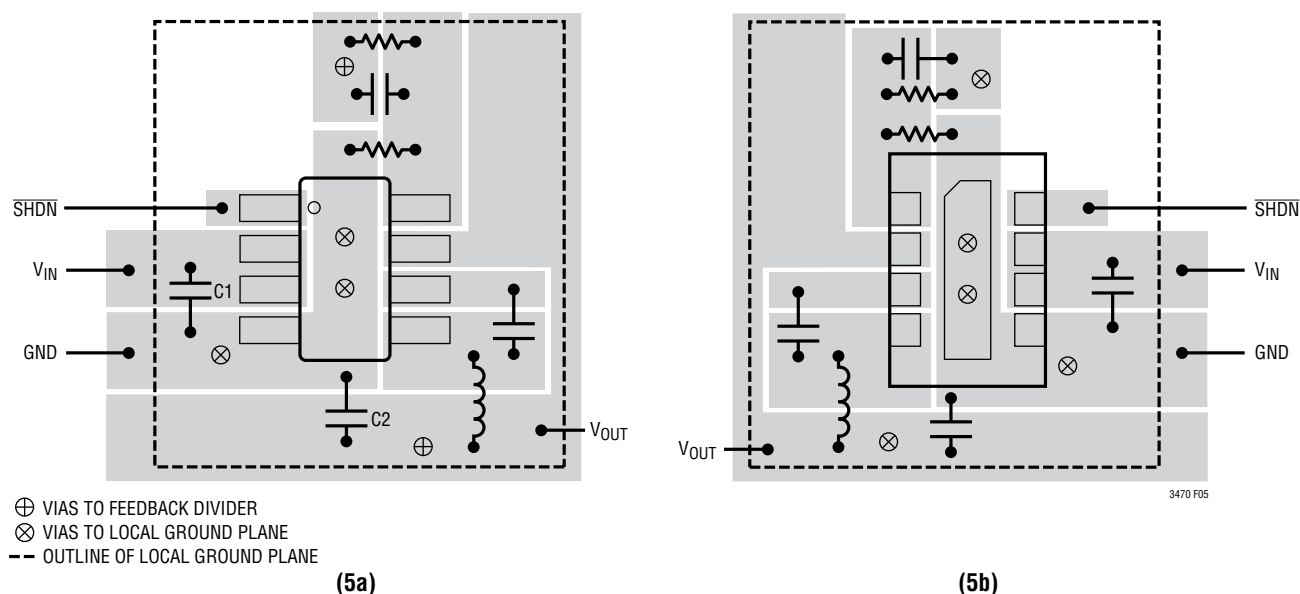


Figure 5. A Good PCB Layout Ensures Proper, Low EMI Operation

APPLICATIONS INFORMATION

Hot-Plugging Safely

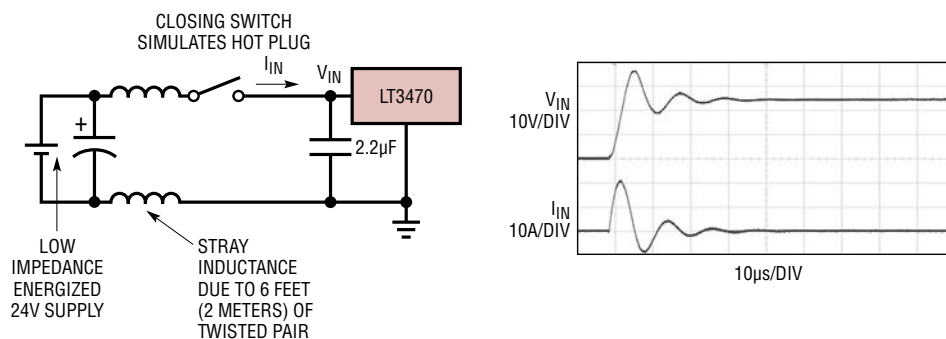
The small size, robustness and low impedance of ceramic capacitors make them an attractive option for the input bypass capacitor of LT3470. However, these capacitors can cause problems if the LT3470 is plugged into a live supply (see Linear Technology Application Note 88 for a complete discussion). The low loss ceramic capacitor combined with stray inductance in series with the power source forms an under damped tank circuit, and the voltage at the V_{IN} pin of the LT3470 can ring to twice the nominal input voltage, possibly exceeding the LT3470's rating and damaging the part. If the input supply is poorly controlled or the user will be plugging the LT3470 into an energized supply, the input network should be designed to prevent this overshoot. Figure 6 shows the waveforms that result when an LT3470 circuit is connected to a 24V supply through six feet of 24-gauge twisted pair. The first plot is the response with a 2.2 μ F ceramic capacitor at the input. The input voltage rings as high as 35V and the input current peaks at 20A. One method of damping the tank circuit is to add another capacitor with a series resistor to the circuit. In Figure 6b an aluminum electrolytic capacitor has been added. This capacitor's high equivalent series resistance damps the circuit and eliminates the voltage overshoot. The extra capacitor improves low frequency ripple filtering and can slightly improve the efficiency of the circuit, though it is likely to be the largest component in the circuit. An alternative solution is shown in Figure 6c. A 1 Ω resistor is added in series with the input to eliminate the voltage overshoot

(it also reduces the peak input current). A 0.1 μ F capacitor improves high frequency filtering. This solution is smaller and less expensive than the electrolytic capacitor. For high input voltages its impact on efficiency is minor, reducing efficiency less than one half percent for a 5V output at full load operating from 24V.

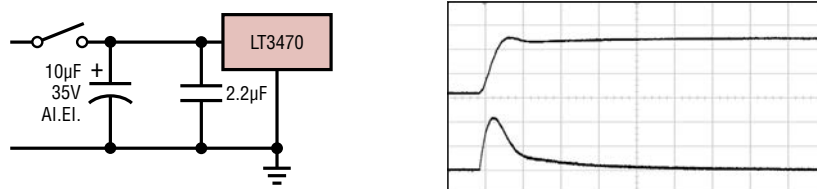
High Temperature Considerations

The die junction temperature of the LT3470 must be lower than the maximum rating of 125°C (150°C for the H-grade). This is generally not a concern unless the ambient temperature is above 85°C. For higher temperatures, care should be taken in the layout of the circuit to ensure good heat sinking of the LT3470. The maximum load current should be derated as the ambient temperature approaches the maximum junction rating. The die temperature is calculated by multiplying the LT3470 power dissipation by the thermal resistance from junction to ambient. Power dissipation within the LT3470 can be estimated by calculating the total power loss from an efficiency measurement. Thermal resistance depends on the layout of the circuit board and choice of package. The DD package with the exposed pad has a thermal resistance of approximately 80°C/W while the ThinSOT is approximately 150°C/W. Finally, be aware that at high ambient temperatures the internal Schottky diode will have significant leakage current (see Typical Performance Characteristics) increasing the quiescent current of the LT3470 converter.

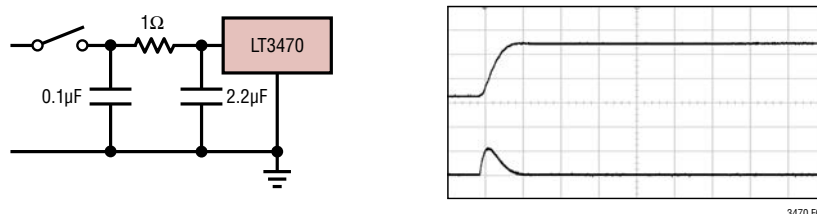
APPLICATIONS INFORMATION



(6a)



(6b)

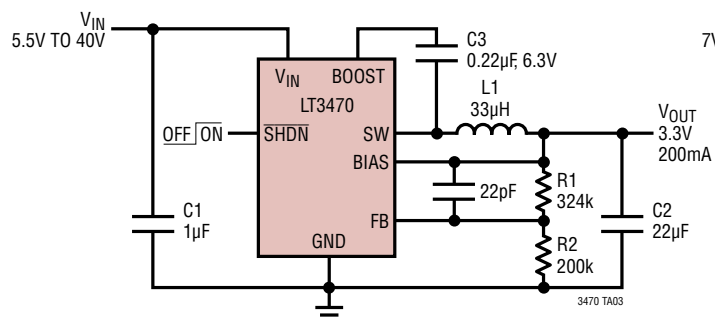


(6c)

Figure 6. A Well Chosen Input Network Prevents Input Voltage Overshoot and Ensures Reliable Operation When the LT3470 Is Connected to a Live Supply

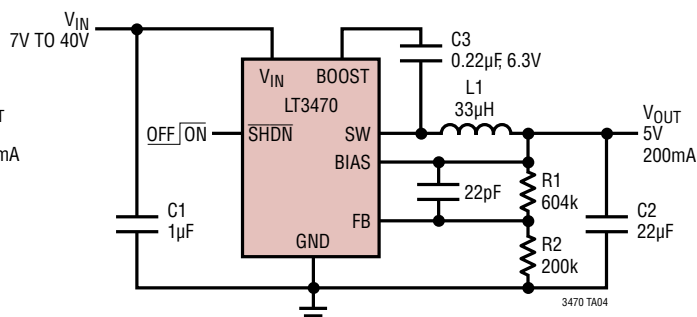
TYPICAL APPLICATIONS

3.3V Step-Down Converter



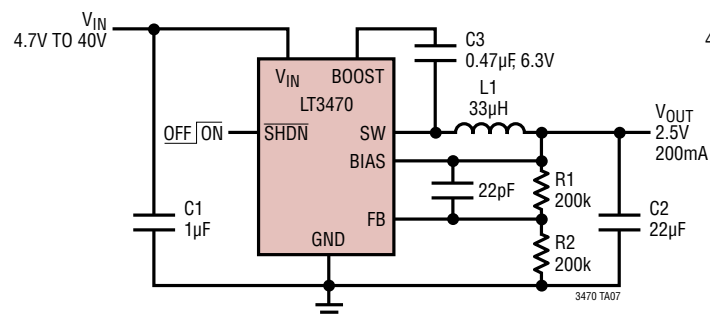
C1: TDK C3216JB1H105M
C2: CE JMK316 BJ226ML-T
L1: TOKO A993AS-270M=P3

5V Step-Down Converter



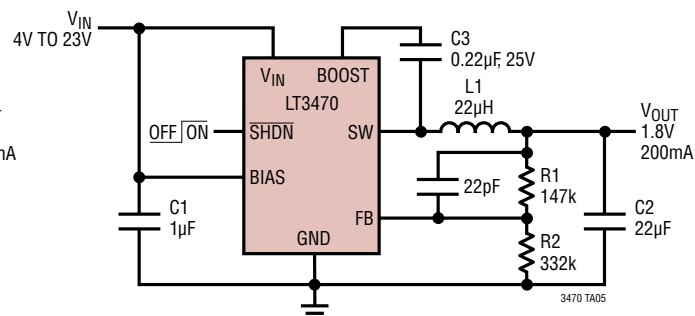
C1: TDK C3216JB1H105M
C2: CE JMK316 BJ226ML-T
L1: TOKO A914BYW-330M=P3

2.5V Step-Down Converter



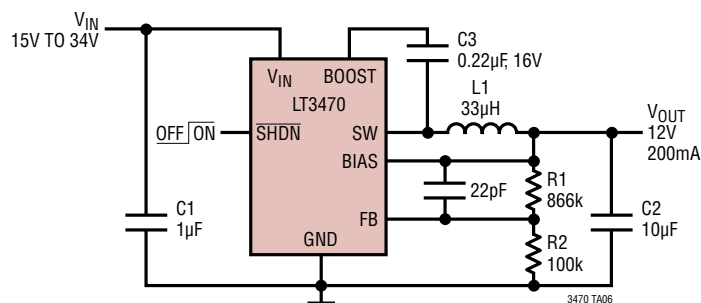
C1: TDK C3216JB1H105M
C2: TDK C2012JB0J226M
L1: SUMIDA CDRH3D28

1.8V Step-Down Converter



C1: TDK C3216JB1H105M
C2: TDK C2012JB0J226M
L1: MURATA LQH32CN150K53

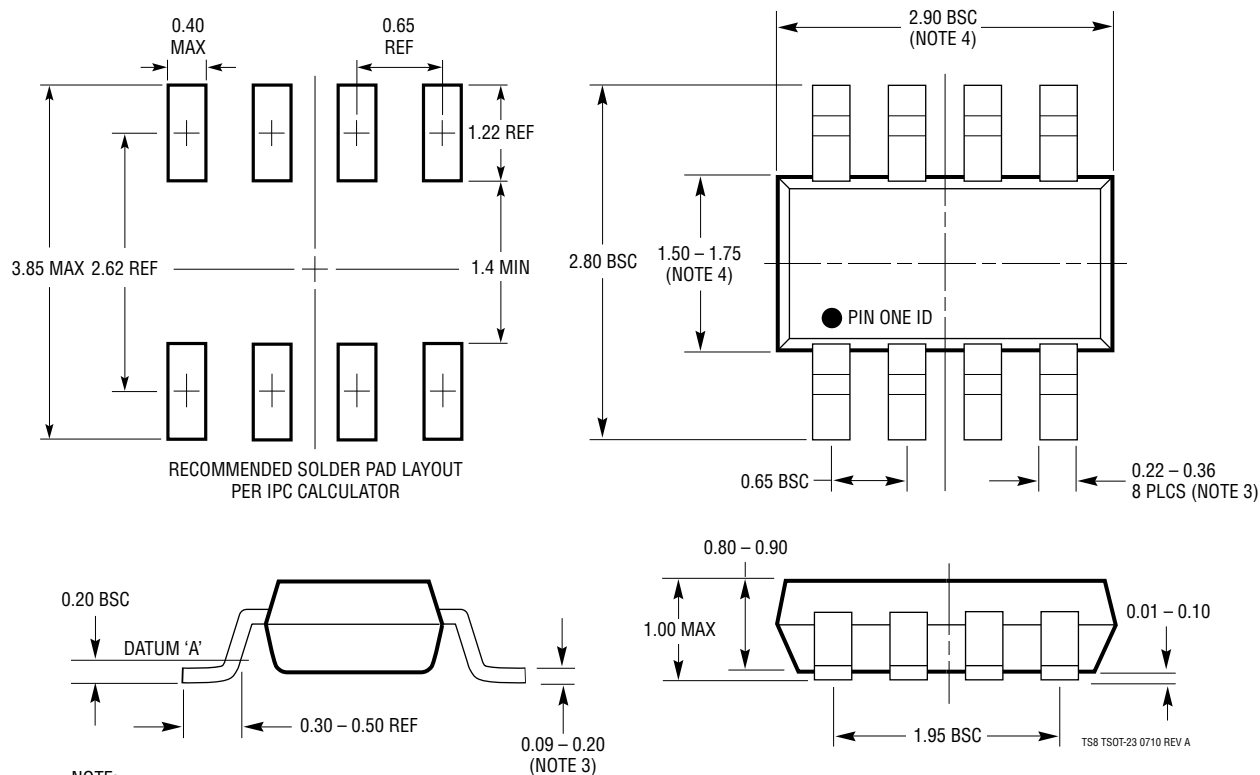
12V Step-Down Converter



C1: TDK C3216JB1H105M
C2: TDK C3216JB1C106M
L1: MURATA LQH32CN150K53

PACKAGE DESCRIPTION

TS8 Package
8-Lead Plastic TSOT-23
 (Reference LTC DWG # 05-08-1637 Rev A)

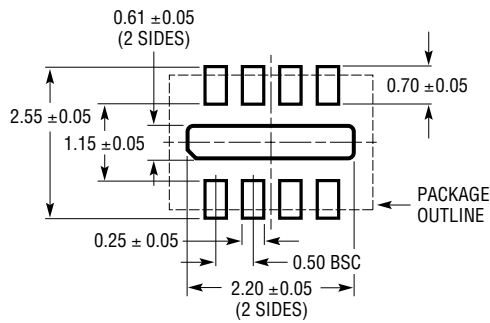


NOTE:

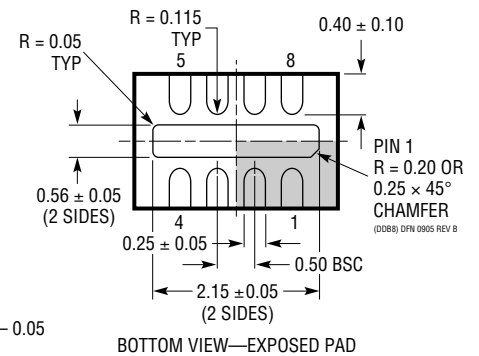
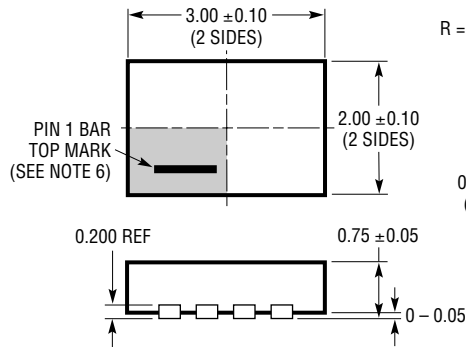
1. DIMENSIONS ARE IN MILLIMETERS
2. DRAWING NOT TO SCALE
3. DIMENSIONS ARE INCLUSIVE OF PLATING
4. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
5. MOLD FLASH SHALL NOT EXCEED 0.254mm
6. JEDEC PACKAGE REFERENCE IS MO-193

PACKAGE DESCRIPTION

DDB Package 8-Lead Plastic DFN (3mm × 2mm) (Reference LTC DWG # 05-08-1702 Rev B)



RECOMMENDED SOLDER PAD PITCH AND DIMENSIONS



NOTE:

1. DRAWING CONFORMS TO VERSION (WECD-1) IN JEDEC PACKAGE OUTLINE M0-229
2. DRAWING NOT TO SCALE
3. ALL DIMENSIONS ARE IN MILLIMETERS
4. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
5. EXPOSED PAD SHALL BE SOLDER PLATED
6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE

REVISION HISTORY (Revision history begins at Rev D)

REV	DATE	DESCRIPTION	PAGE NUMBER
D	09/11	Corrected lead-based tape and reel part numbers in the Order Information section.	2
E	04/20	Added AEC-Q100 Qualified.	1
		Added #W options for automotive under Order Information.	3
		Updated Inductor vendors table.	10

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1616	25V, 500mA (I_{OUT}), 1.4MHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 3.6V$ to 25V, $V_{OUT} = 1.25V$, $I_Q = 1.9mA$, $I_{SD} < 1\mu A$, ThinSOT Package
LT1676	60V, 440mA (I_{OUT}), 100kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 7.4V$ to 60V, $V_{OUT} = 1.24V$, $I_Q = 3.2mA$, $I_{SD} = 2.5\mu A$, S8 Package
LT1765	25V, 2.75A (I_{OUT}), 1.25MHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 3V$ to 25V, $V_{OUT} = 1.2V$, $I_Q = 1mA$, $I_{SD} = 15\mu A$, S8, TSSOP16E Packages
LT1766	60V, 1.2A (I_{OUT}), 200kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 5.5V$ to 60V, $V_{OUT} = 1.2V$, $I_Q = 2.5mA$, $I_{SD} = 25\mu A$, TSSOP16/E Package
LT1767	25V, 1.2A (I_{OUT}), 1.25MHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 3V$ to 25V; $V_{OUT} = 1.2V$, $I_Q = 1mA$, $I_{SD} = 6\mu A$, MS8/E Packages
LT1776	40V, 550mA (I_{OUT}), 200kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 7.4V$ to 40V; $V_{OUT} = 1.24V$, $I_Q = 3.2mA$, $I_{SD} = 30\mu A$, N8, S8 Packages
LTC®1877	600mA (I_{OUT}), 550kHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.7V$ to 10V; $V_{OUT} = 0.8V$, $I_Q = 10\mu A$, $I_{SD} \leq 1\mu A$, MS8 Package
LTC1879	1.2A (I_{OUT}), 550kHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.7V$ to 10V; $V_{OUT} = 0.8V$, $I_Q = 15\mu A$, $I_{SD} \leq 1\mu A$, TSSOP16 Package
LT1933	36V, 600mA, 500kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 3.6V$ to 36V; $V_{OUT} = 1.25V$, $I_Q = 2.5\mu A$, $I_{SD} \leq 1\mu A$, ??? Package
LT1934	34V, 250mA (I_{OUT}), Micropower, Step-Down DC/DC Converter	$V_{IN} = 3.2V$ to 34V; $V_{OUT} = 1.25V$, $I_Q = 12\mu A$, $I_{SD} \leq 1\mu A$, ??? Package
LT1956	60V, 1.2A (I_{OUT}), 500kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 5.5V$ to 60V, $V_{OUT} = 1.2V$, $I_Q = 2.5mA$, $I_{SD} = 25\mu A$, TSSOP16/E Package
LTC3405/LTC3405A	300mA (I_{OUT}), 1.5MHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.7V$ to 6V, $V_{OUT} = 0.8V$, $I_Q = 20\mu A$, $I_{SD} \leq 1\mu A$, ThinSOT Package
LTC3406/LTC3406B	600mA (I_{OUT}), 1.5MHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.5V$ to 5.5V, $V_{OUT} = 0.6V$, $I_Q = 20\mu A$, $I_{SD} \leq 1\mu A$, ThinSOT Package
LTC3411	1.25A (I_{OUT}), 4MHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.5V$ to 5.5V, $V_{OUT} = 0.8V$, $I_Q = 60\mu A$, $I_{SD} \leq 1\mu A$, MS Package
LTC3412	2.5A (I_{OUT}), 4MHz, Synchronous Step-Down DC/DC Converter	$V_{IN} = 2.5V$ to 5.5V, $V_{OUT} = 0.8V$, $I_Q = 60\mu A$, $I_{SD} \leq 1\mu A$, TSSOP16E Package
LTC3430	60V, 2.75A (I_{OUT}), 200kHz, High Efficiency Step-Down DC/DC Converter	$V_{IN} = 5.5V$ to 60V, $V_{OUT} = 1.2V$, $I_Q = 2.5mA$, $I_{SD} = 30\mu A$, TSSOP16E Package